

JFET Input Operational Amplifiers

These low cost JFET input operational amplifiers combine two state—of—the—art analog technologies on a single monolithic integrated circuit. Each internally compensated operational amplifier has well matched high voltage JFET input devices for low input offset voltage. The JFET technology provides wide bandwidths and fast slew rates with low input bias currents, input offset currents, and supply currents.

These devices are available in single, dual and quad operational amplifiers which are pin-compatible with the industry standard MC1741, MC1458, and the MC3403/LM324 bipolar devices.

• Input Offset Voltage of 5.0 mV Max (LF347B)

• Low Input Bias Current: 50 pA

Low Input Noise Voltage: 16 nV/√Hz
 Wide Gain Bandwidth: 4.0 MHz

• High Slew Rate: 13V/μs

• Low Supply Current: 1.8 mA per Amplifier

High Input Impedance: 10¹² Ω

• High Common Mode and Supply Voltage Rejection Ratios: 100 dB

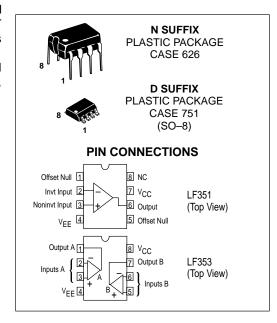
MAXIMUM RATINGS

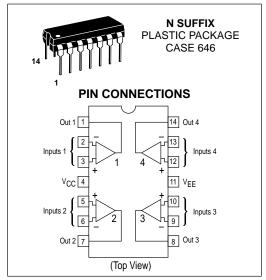
Rating	Symbol	Value	Unit
Supply Voltage	V _{CC}	+18 -18	V
Differential Input Voltage	V _{ID}	±30	V
Input Voltage Range (Note 1)	V _{IDR}	±15	V
Output Short Circuit Duration (Note 2)	tsc	Continuous	
Power Dissipation at T _A = +25°C Derate above T _A =+25°C	P _D 1/ ₀ JA	900 10	mW mW/°C
Operating Ambient Temperature Range	T _A	0 to +70	°C
Operating Junction Temperature Range	TJ	115	°C
Storage Temperature Range	T _{stg}	- 65 to +150	°C

NOTES: 1. Unless otherwise specified, the absolute maximum negative input voltage is limited to the negative power supply.

LF347, B LF351 LF353

FAMILY OF JFET OPERATIONAL AMPLIFIERS





ORDERING INFORMATION

Device	Function	Operating Temperature Range	Package		
LF351D	Single		SO-8		
LF351N	Single		Plastic DIP		
LF353D	Dual	$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$	SO-8		
LF353N	Dual		Plastic DIP		
LF347BN	Quad		Plastic DIP		
LF347N	Quad		Plastic DIP		

Any amplifier output can be shorted to ground indefinitely. However, if more than one amplifier output is shorted simultaneously, maximum junction temperature rating may be exceeded.

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ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V_{EE} = -15 V_{CC} = -15 V_{CC} , unless otherwise noted.)

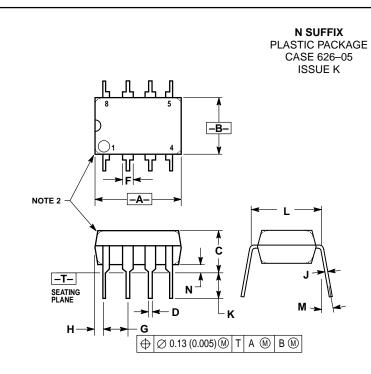
		LF347B		LF347, LF351, LF353				
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (R _S \leq 10 k, V _{CM} = 0) T _A = +25°C 0°C \leq T _A \leq +70°C	VIO	- -	1.0 -	5.0 8.0	- -	5.0 –	10 13	mV
Avg. Temperature Coefficient of Input Offset Voltage $R_S \le 10 \text{ k}, 0^{\circ}\text{C} \le T_A \le +70^{\circ}\text{C}$	ΔV _{ΙΟ} /ΔΤ	_	10	_	_	10	_	μV/°C
Input Offset Current ($V_{CM} = 0$, Note 3) $T_A = +25^{\circ}C$ $0^{\circ}C \le T_A \le +70^{\circ}C$	lιο	_ _	25 -	100 4.0	_ _	25 -	100 4.0	pA nA
Input Bias Current ($V_{CM} = 0$, Note 3) $T_A = +25^{\circ}C$ $0^{\circ}C \le T_A \le +70^{\circ}C$	I _{IB}	- -	50 -	200 8.0	- -	50 -	200 8.0	pA nA
Input Resistance	rį	_	10 ¹²	_	_	1012	_	Ω
Common Mode Input Voltage Range	VICR	±11	+15 -12	-	±11	+15 -12	-	V
Large–Signal Voltage Gain ($V_O = \pm 10 \text{ V}$, $R_L = 2.0 \text{ k}$) $T_A = +25^{\circ}\text{C}$ $0^{\circ}\text{C} \le T_A \le +70^{\circ}\text{C}$	AVOL	50 25	100 -	_ _	25 15	100 -	_ _	V/mV
Output Voltage Swing (R _L = 10 k)	VO	±12	±14	-	±12	±14	_	V
Common Mode Rejection (R _S ≤ 10 k)	CMR	80	100	-	70	100	_	dB
Supply Voltage Rejection (R _S ≤ 10 k)	PSRR	80	100	-	70	100	-	dB
Supply Current LF347 LF351 LF353	ID	- - -	7.2 - -	11 - -	- - -	7.2 1.8 3.6	11 3.4 6.5	mA
Short Circuit Current	Isc	-	25	-	_	25	_	mA
Slew Rate (A _V = +1)	SR	-	13	-	_	13	-	V/μs
Gain-Bandwidth Product	BWp	-	4.0	-	_	4.0	-	MHz
Equivalent Input Noise Voltage (RS = 100 Ω , f = 1000 Hz)	e _n	-	24	-	-	24	-	nV/√Hz
Equivalent Input Noise Current (f = 1000 Hz)	in	-	0.01	-	-	0.01	-	pA/√Hz
Channel Separation (LF347, LF353) 1.0 Hz \leq f \leq 20 kHz (Input Referred)	_	_	-120	_	-	-120	-	dB

For Typical Characteristic Performance Curves, refer to MC34001, 34002, 34004 data sheet.

NOTE: 3. Input bias currents of JFET input op amps approximately double for every 10°C rise in junction temperature. To maintain junction temperatures as close to ambient as is possible, pulse techniques are utilized during test.

LF347, B LF351 LF353

OUTLINE DIMENSIONS

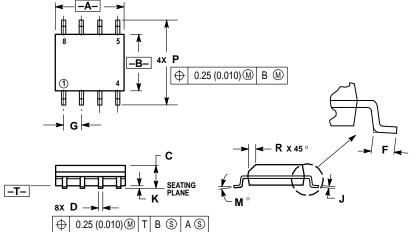


- NOTES:
 1. DIMENSION L TO CENTER OF LEAD WHEN
- FORMED PARALLEL.

 2. PACKAGE CONTOUR OPTIONAL (ROUND OR
- 2. PACKAGE CONTIGUE OF HUMAL (ROUND ON SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIMETERS		INCHES		
DIM	MIN	MIN MAX		MAX	
Α	9.40	10.16	0.370	0.400	
В	6.10	6.60	0.240	0.260	
С	3.94	4.45	0.155	0.175	
D	0.38	0.51	0.015	0.020	
F	1.02	1.78	0.040	0.070	
G	2.54	BSC	0.100 BSC		
Н	0.76	1.27	0.030	0.050	
J	0.20	0.30	0.008	0.012	
K	2.92	3.43	0.115	0.135	
L	7.62 BSC		0.300 BSC		
M		10°		10°	
N	0.76	1.01	0.030	0.040	





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DED SIDE
- PER SIDE.

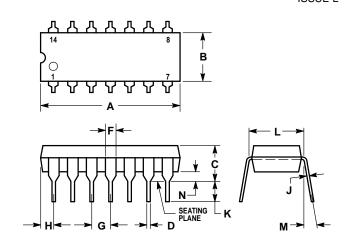
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION. SHALL BE 0.127 (0.005) TOTAL
 IN EXCESS OF THE D DIMENSION AT
 MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.196
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.18	0.25	0.007	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

LF347, B LF351 LF353

OUTLINE DIMENSIONS

N SUFFIX PLASTIC PACKAGE CASE 646-06 ISSUE L



NOTES:

- LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- 3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- 4. ROUNDED CORNERS OPTIONAL.

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	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	19.56	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
K	0.115	0.135	2.92	3.43	
L	0.300 BSC		7.62 BSC		
М	0°	10°	0°	10°	
N	0.015	0.039	0.39	1.01	

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